

NP35N055YUK

55 V – 35 A – N-channel Power MOS FET Application: Automotive R07DS1002EJ0200 Rev.2.00 May 24, 2018

Description

The NP35N055YUK is N-channel MOS Field Effect Transistors designed for high current switching applications.

Features

- Super low on-state resistance
 - $R_{DS(on)} = 6.7 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 18 \text{ A})$
- Non logic level drive type
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Pac	Package	
NP35N055YUK-E1-AY *1	Pure Sn (Tin)	Tape 2500 p/reel	Taping (E1 type)	8-pin HSON
NP35N055YUK-E2-AY *1			Taping (E2 type)	

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

ltem	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 V$)	V _{DSS}	55	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) (T _C = 25°C)	I _{D(DC)}	±35	A
Drain Current (pulse) *1, 4	I _{D(pulse)}	±140	A
Total Power Dissipation ($T_c = 25^{\circ}C$)	P _{T1}	97	W
Total Power Dissipation ($T_A = 25^{\circ}C$) *2	P _{T2}	1.0	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	-55 to +175	°C
Repetitive Avalanche Current *3, 4	I _{AR}	24	A
Repetitive Avalanche Energy *3, 4	E _{AR}	58	mJ

Thermal Resistance

Channel to Case Thermal Resistance	Rth(ch-C)*4	1.55	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *4	150	°C/W

Notes: *1 $~T_C$ = 25°C, $P_W \leq$ 10 $\mu s,~Duty~Cycle \leq$ 1%

*2 Mounted on glass epoxy substrate of 40 mm \times 40 mm \times 1.6 mmt with 4% Copper area (35 $\mu m)$

- *3 R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V
- *4. Not subject of production test. Verified by design/characterization.



Electrical Characteristics	$(T_{A} = 25^{\circ}C)$
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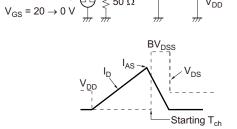
Symbol	MIN	TYP	ΜΔΧ	Unit	Test Conditions	
			1		$V_{DS} = 55 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	
			+100		$V_{\rm DS} = 30$ V, $V_{\rm GS} = 0$ V $V_{\rm GS} = \pm 20$ V, $V_{\rm DS} = 0$ V	
-	2.0	3.0			$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = 250 \mu\text{A}$	
				-	$V_{DS} = 5 \text{ V}, \text{ I}_D = 18 \text{ A}$	
			6.7	_	$V_{GS} = 10 \text{ V}, \text{ I}_D = 18 \text{ A}$	
1		2240	3360	pF	$V_{DS} = 25 V$	
		230	350	pF	$V_{GS} = 0 V$	
Crss		95	180	pF	f = 1 MHz	
t _{d(on)}		19	38	ns	V _{DD} = 28 V, I _D = 18 A	
tr		9	22	ns	V _{GS} = 10 V	
t _{d(off)}		47	94	ns	$R_G = 0 \Omega$	
t _f		4	10	ns		
Q_{G}		38	57	nC	V _{DD} = 44 V	
Q_{GS}		10		nC	V _{GS} = 10 V	
Q _{GD}		10	_	nC	I _D = 35 A	
V _{F(S-D)}		0.9	1.5	V	I _F = 35 A, V _{GS} = 0 V	
trr		35	_	ns	I _F = 35 A, V _{GS} = 0 V	
Qrr		41	_	nC	di/dt = 100 A/μs	
	td(on) tr td(off) tf QG QGD VF(S-D) trr	IDSS IGSS VGS(th) 2.0 yfs 18 RDS(on) Ciss Coss Crss td(on) tfr QG QGS VF(S-D) trr	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

Note: *1 Pulsed test

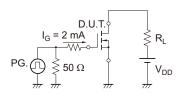
Note: *2 Not subject of production test. Verified by design/characterization.

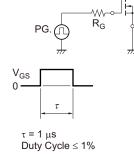
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$PG. \square \leq 50 \Omega$



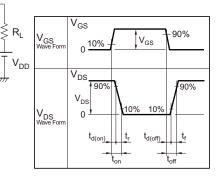
TEST CIRCUIT 3 GATE CHARGE





TEST CIRCUIT 2 SWITCHING TIME

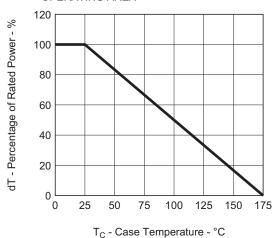
D.U.T.

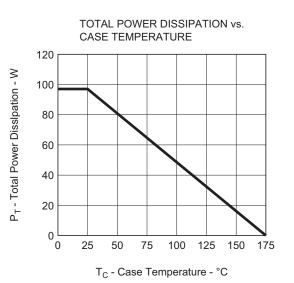




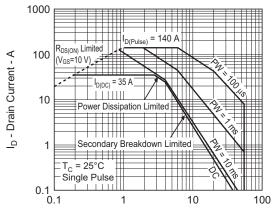
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



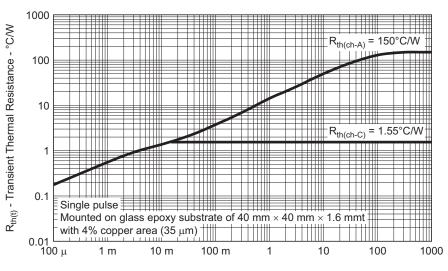


FORWARD BIAS SAFE OPERATING AREA



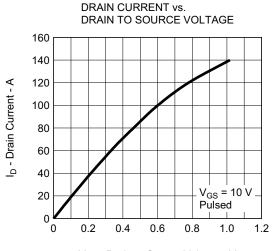




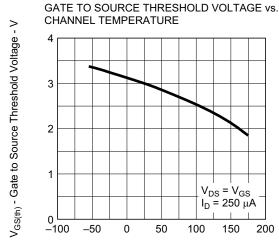


PW - Pulse Width - s

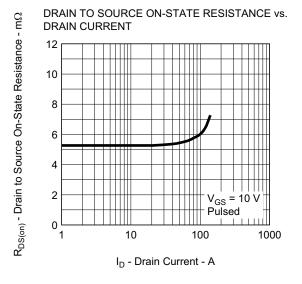




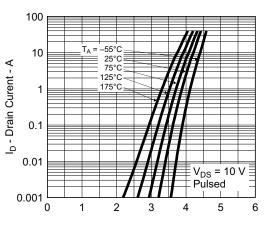
V_{DS} - Drain to Source Voltage - V



T_{ch} - Channel Temperature - °C

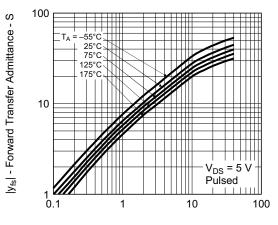


FORWARD TRANSFER CHARACTERISTICS

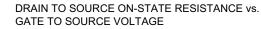


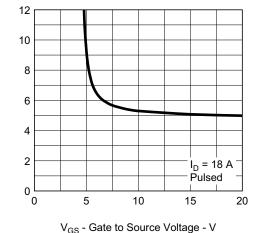


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



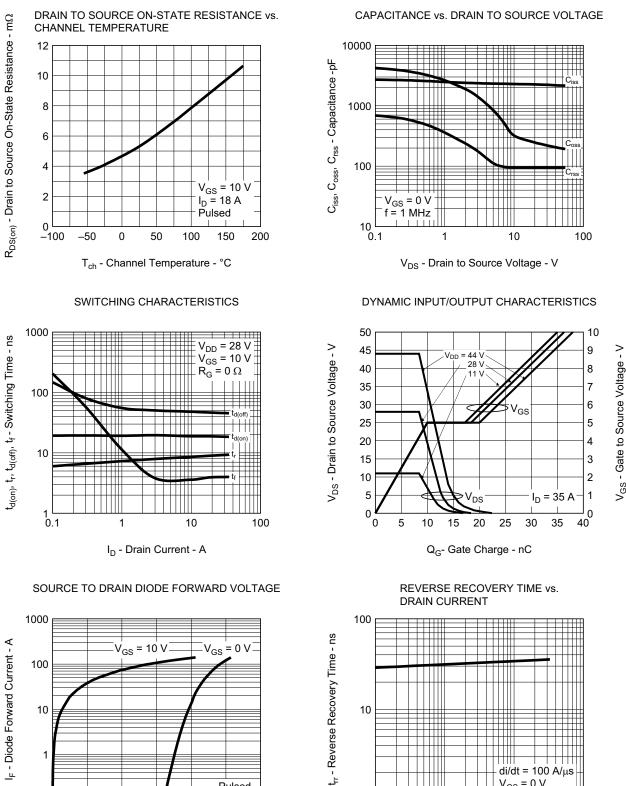
I_D - Drain Current - A

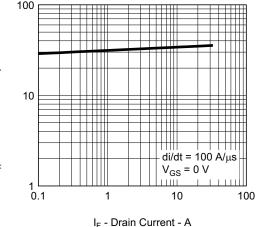




 $R_{DS(on)}$ - Drain to Source On-State Resistance - $m\Omega$

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1

0.1

0

0.2

0.4

0.6

 $V_{F(S-D)}$ - Source to Drain Voltage - V

0.8



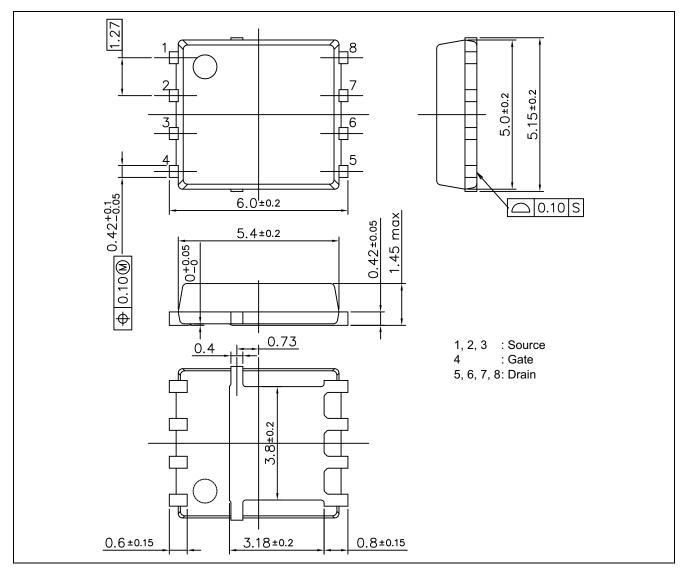
Pulsed

1.2

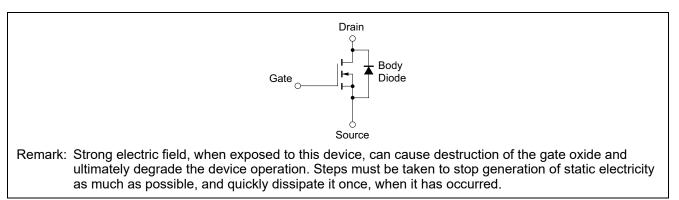
1.0

Package Drawing (Unit: mm)

8-pin HSON (Mass: 0.128 g TYP.)



Equivalent Circuit





Revision History

NP35N055YUK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Feb 08, 2013	—	First Edition Issued	
2.00	May 24 ,2018	1	Note 4 was added	
		2	Note 2 was added	

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